

R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. These techniques are described in "[A Simple Method of Generating Thermal Models for a Power MOSFET](#)"[1]. When implemented in P-Spice, these values have matching characteristic curves to the Single Pulse Transient Thermal Impedance curves for the MOSFET.

R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included.

Note:

For a detailed explanation of implementing these values in P-SPICE, refer to [Application Note AN609 Thermal Simulations Of Power MOSFETs on P-SPICE Platform](#).

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RT1	8.5628	N/A	4.3111
RT2	15.1066	N/A	4.5189
RT3	16.3180	N/A	6.0710
RT4	50.0126	N/A	13.0990
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	5.2387 m	N/A	2.9964 m
CT2	194.5908 m	N/A	19.3806 m
CT3	53.1843 m	N/A	35.8823 m
CT4	1.4393	N/A	93.7186 m

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance ($^{\circ}\text{C}/\text{W}$)			
Junction to	Ambient	Case	Foot
RF1	9.1998	N/A	2.7723
RF2	16.7783	N/A	12.1472
RF3	19.1285	N/A	5.7912
RF4	44.8934	N/A	7.2893
Thermal Capacitance (Joules/ $^{\circ}\text{C}$)			
Junction to	Ambient	Case	Foot
CF1	4.1965 m	N/A	1.2311 m
CF2	26.0063 m	N/A	6.2556 m
CF3	111.6508 m	N/A	43.3312 m
CF4	1.5282	N/A	107.9422 m

Note: NA indicates not applicable

Reference:

[1] "A Simple Method of Generating Thermal Models for a Power MOSFET" by Wharton McDaniel and Kandarp Pandya. IEEE / SEMITHERM 2002

